## NSN 5961-01-095-8473

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Inclosure Material:
Metal
Overall Length:
0.260 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.335 inches
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
То-39
Mounting Method:
Terminal
Terminal Circle Diameter:
0.210 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
250.0 collector to emitter voltage, dc and 250.0 collector to base voltage, dc and 7.0 emitter to base voltage, dc
Current Rating Per Characteristic:
50.00 milliamperes source cutoff current
Power Rating Per Characteristic:
1.0 watts small-signal input power, common-collector absolute
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Precious Material And Location:
External surfaces gold
Precious Material:
Gold
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No

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